LOW-VOLTAGE 24-BIT BUS EXCHANGE SWITCH

IDT74CBTLV16212

FEATURES:

- **5Ω A/B bi-directional switch**
- **Isolation Under Power-Off Conditions**
- **Over-voltage tolerant**
- **Latch-up performance exceeds 100mA**
- **Vcc = 2.3V - 3.6V, normal range**
- **ESD >2000V per MIL-STD-883, Method 3015; >200V using machine model (C = 200pF, R = 0)**
- **Available in SSOP, TSSOP, and TVSOP packages**

APPLICATIONS:

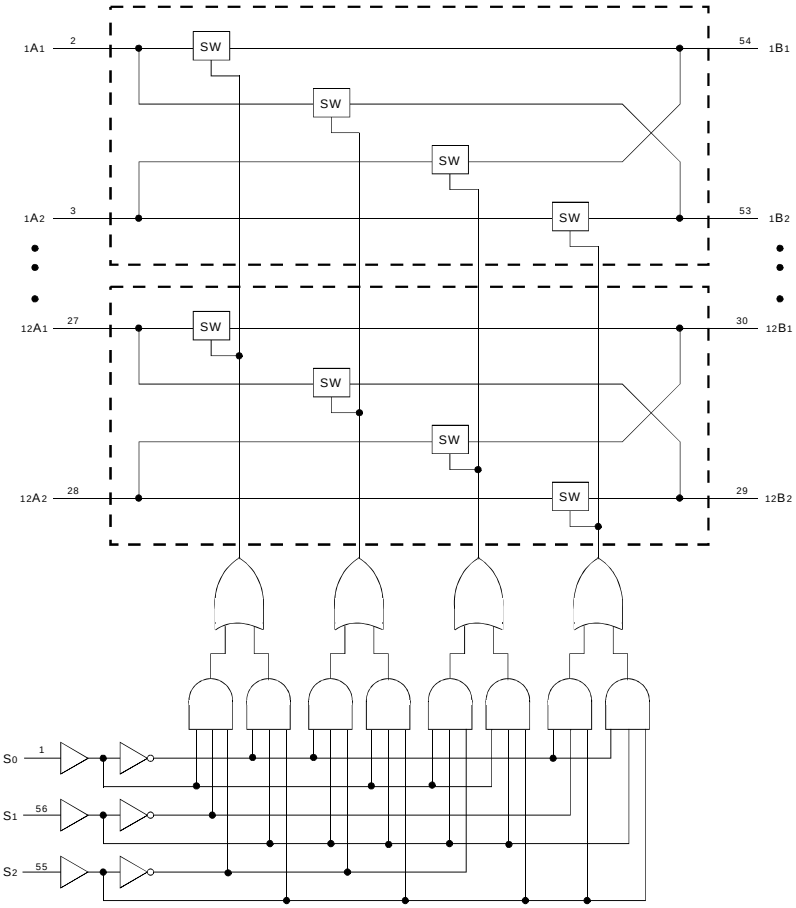
- **3.3V High Speed Bus Switching and Bus Isolation**

DESCRIPTION:

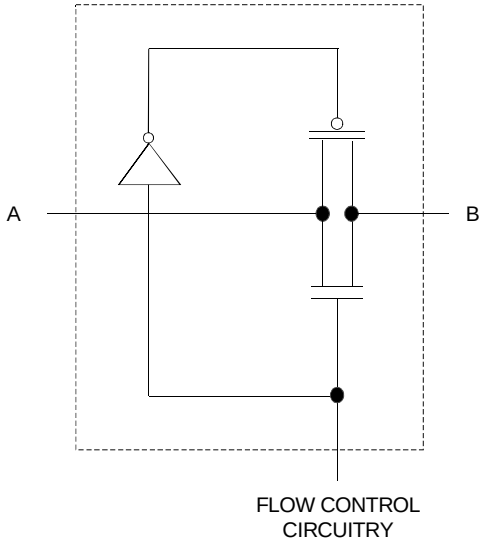
The CBTLV16212 provides a set of 24 high-speed switches for bus exchanging and switching. The device has low ON resistance, resulting in under 250ps propagation delay through the switch. The CBTLV16212 operates as a single 24-bit bus switch or as a 12-bit bus exchanger, which provides data exchanging between the four signal ports through the data select (S_0-S_2) pins.

The CBTLV16212 has the break-before-make feature, which allows zero current when switching between ports B1 and B2.

FUNCTIONAL BLOCK DIAGRAM



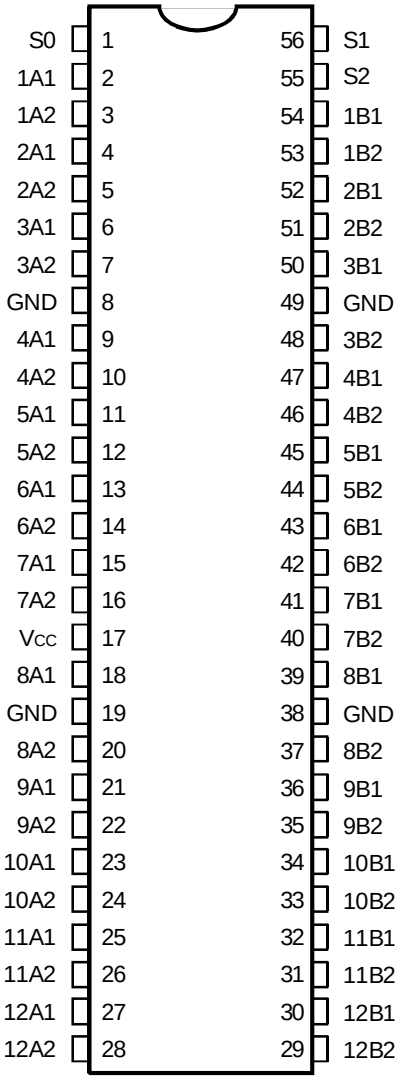
SIMPLIFIED SCHEMATIC, EACH SWITCH



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PIN CONFIGURATION



SSOP/ TSSOP/ TVSOP
TOP VIEW

ABSOLUTE MAXIMUM RATINGS(1)

Symbol	Description	Max.	Unit
V_{CC}	Supply Voltage Range	–0.5 to 4.6	V
V_I	Input Voltage Range	–0.5 to 4.6	V
	Continuous Channel Current	128	mA
I_{IK}	Input Clamp Current, $V_{I/O} < 0$	–50	mA
T_{STG}	Storage Temperature Range	–65 to +150	°C

NOTE:
1. Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

PIN DESCRIPTION

Pin Names	Description
Sx	Data Select
xAx	Port A Inputs or Outputs
xBx	Port B Inputs or Outputs

FUNCTION TABLE(1)

Inputs			Inputs/Outputs		
S_2	S_1	S_0	A_1	A_2	Operation
L	L	L	Z	Z	Disconnect
L	L	H	B_1	Z	A_1 port = B_1 port
L	H	L	B_2	Z	A_1 port = B_2 port
L	H	H	Z	B_1	A_2 port = B_1 port
H	L	L	Z	B_2	A_2 port = B_2 port
H	L	H	Z	Z	Disconnect
H	H	L	B_1	B_2	A_1 port = B_1 port A_2 port = B_2 port
H	H	H	B_2	B_1	A_1 port = B_2 port A_2 port = B_1 port

NOTE:
1. H = HIGH Voltage Level
   L = LOW Voltage Level
   Z = High-Impedance

OPERATING CHARACTERISTICS(1)

Symbol	Parameter	Test Conditions	Min.	Max.	Unit
V_{CC}	Supply Voltage		2.3	3.6	V
V_{IH}	High-Level Control Input Voltage	V_{CC} = 2.3V to 2.7V	1.7	—	V
		V_{CC} = 2.7V to 3.6V	2	—	
V_{IL}	Low-Level Control Input Voltage	V_{CC} = 2.3V to 2.7V	—	0.7	V
		V_{CC} = 2.7V to 3.6V	—	0.8	
T_A	Operating Free-Air Temperature		–40	+85	°C

NOTE:
1. All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation.

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified:
Operating Condition: T_A = –40°C to +85°C

Symbol	Parameter	Test Conditions		Min.	Typ.(1)	Max.	Unit
V_{IK}	Control Inputs, Data I/O	V_{CC} = 3V, I_I = –18mA		—	—	–1.2	V
I_I	Control Inputs	V_{CC} = 3.6V, V_I = V_{CC} or GND		—	—	±1	µA
I_{OZ}	Data I/O	V_{CC} = 3.6V, V_O = 0V or 3.6V switch disabled		—	—	5	µA
I_{OFF}		V_{CC} = 0V, V_I or V_O = 0V or 3.6V		—	—	10	µA
I_{CC}		V_{CC} = 3.6V, I_O = 0, V_I = V_{CC} or GND		—	—	10	µA
ΔI_{CC}(2)	Control Inputs	V_{CC} = 3.6V, one input at 3V, other inputs at V_{CC} or GND		—	—	300	µA
C_I	Control Inputs	V_I = 3V or 0		—	5	—	pF
$C_{IO(OFF)}$		V_O = 3V or 0 (switch off)		—	13.5	—	pF
R_{ON}(3)	Max. at V_{CC} = 2.3V Typ. at V_{CC} = 2.5V	V_I = 0	I_O = 64mA	—	5	8	Ω
			I_O = 24mA	—	5	8	
		V_I = 1.7V	I_O = 15mA	—	27	40	
	V_{CC} = 3V	V_I = 0	I_O = 64mA	—	5	7	
			I_O = 24mA	—	5	7	
		V_I = 2.4V	I_O = 15mA	—	10	15	

NOTES:

1. Typical values are at 3.3V, +25°C ambient.
2. The increase in supply current is attributable to each input that is at the specified voltage level rather than V_{CC} or GND.
3. This is measured by the voltage drop between the A and B terminals at the indicated current through the switch.

SWITCHING CHARACTERISTICS

Symbol	Parameter	V_{CC} = 2.5V ± 0.2V		V_{CC} = 3.3V ± 0.3V		Unit
		Min.	Max.	Min.	Max.	
t_{PD}(1)	Propagation Delay A to B or B to A	—	0.15	—	0.25	ns
t_{PD}	Propagation Delay S to A or B	3	11.1	3	8.8	ns
t_{EN}	Output Enable Time S to A or B	3	10.9	3	8.6	ns
t_{DIS}	Output Disable Time S to A or B	1	8.7	2	8.8	ns

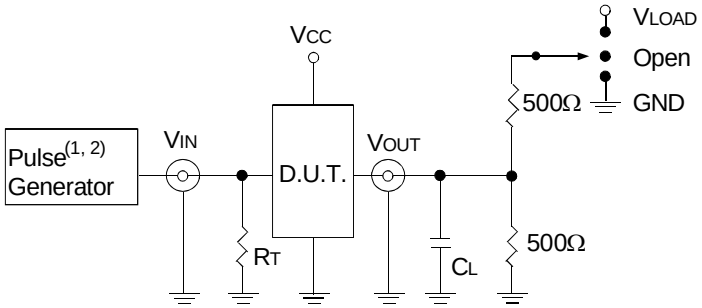
NOTE:

1. The propagation delay is the calculated RC time constant of the typical on-state resistance of the switch and the specified load capacitance when driven by an ideal voltage source (zero output impededance).

TEST CIRCUITS AND WAVEFORMS

TEST CONDITIONS

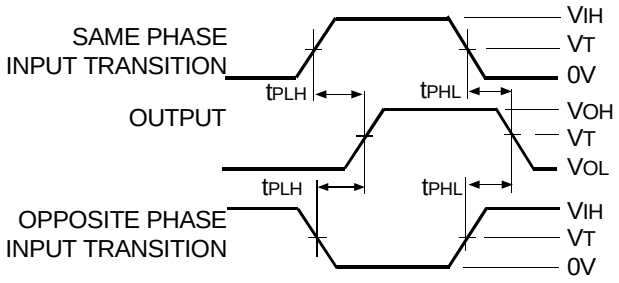
Symbol	$V_{CC}^{(1)}$ = 3.3V±0.3V	$V_{CC}^{(2)}$ = 2.5V±0.2V	Unit
V_{LOAD}	6	2 x Vcc	V
V_{IH}	3	Vcc	V
V_T	1.5	Vcc / 2	V
V_{LZ}	300	150	mV
V_{HZ}	300	150	mV
C_L	50	30	pF



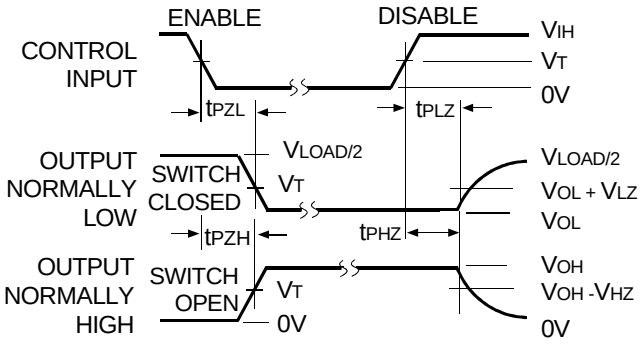
Test Circuits for All Outputs

DEFINITIONS:
C_L = Load capacitance: includes jig and probe capacitance.
R_T = Termination resistance: should be equal to Z_{OUT} of the Pulse Generator.

NOTES:
1. Pulse Generator for All Pulses: Rate ≤ 10MHz; t_F ≤ 2.5ns; t_R ≤ 2.5ns.
2. Pulse Generator for All Pulses: Rate ≤ 10MHz; t_F ≤ 2ns; t_R ≤ 2ns.



Propagation Delay



NOTE:
1. Diagram shown for input Control Enable-LOW and input Control Disable-HIGH.

Enable and Disable Times

SWITCH POSITION

Test	Switch
t_{PLZ}/t_{PZL}	V_{LOAD}
t_{PHZ}/t_{PZH}	GND
t_{PD}	Open

ORDERING INFORMATION

IDT XX CBTLV XXX XX

Temp. Range | Device Type | Package

PV	Shrink Small Outline Package
PA	Thin Shrink Small Outline Package
PAG	TSSOP - Green
PF	Thin Very Small Outline Package

16212	Low-Voltage 24-Bit Bus Exchange Switch

74	–40°C to +85°C

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